**DOCKET NO: 220327US2** 



## IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

YASUHIKO MATSUNAGA ET AL.

: EXAMINER: YOHA, C. C.

SERIAL NO: 10/090,995

FILED: MARCH 6, 2002

: GROUP ART UNIT: 2818

FOR: NON-VOLATILE

SEMICONDUCTOR MEMORY

**DEVICE** 

## **AMENDMENT**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated December 8, 2003, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 4 of this paper.

Amendments to the Drawings begin on page 17 of this paper and include an attached replacement sheet.

Remarks/Arguments begin on page 18 of this paper.

05/10/2004 HVUONG1 00000087 10090995

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